

Schottky Barrier Diode DB2141300L

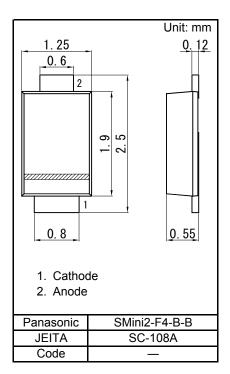
DB2141300L Silicon epitaxial planar type

For rectification

- Features
- Low forward voltage and small reverse leakage current
- Forward current (Average) IF(AV) = 2 A rectification is possible
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)
- Marking Symbol: 4N

Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

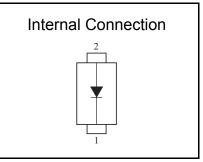


■ Absolute Maximum Ratings Ta = 25 °C

	-		
Parameter	Symbol	Rating	Unit
Reverse voltage (direct current)	VR	40	V
Forward current (average) ^{*1}	IF(AV)	2.0	А
Non-repetitive peak forward surge current *2	IFSM	30	А
Junction temperature ^{*1}	Tj	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C
Note: *1 TI = 80 °C			

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*2 50 Hz sine wave 1 cycle (Non-repetitive peak current)



Panasonic

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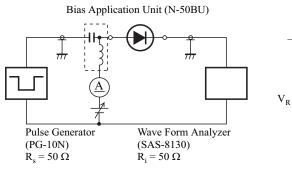
■ Electrical Characteristics Ta = 25 °C ± 3 °C

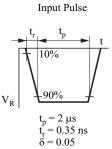
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Forward voltage	VF	IF = 2.0 A		0.46	0.53	V
Reverse current	IR	VR = 40 V		25	150	μA
Terminal capacitance	Ct	VR = 10 V, f = 1 MHz		43		pF
Reverse recovery time ^{*1}	trr	IF = IR = 100 mA, Irr = 10 mA		12		ns

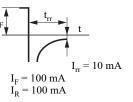
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 Measuring methods for Diodes.

 This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. *1 trr test circuit







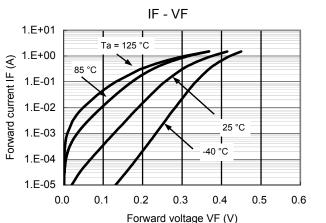
Output Pulse

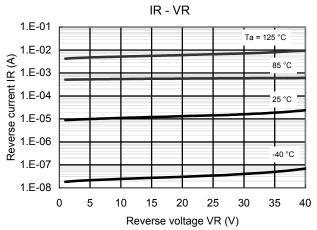
Established : 2009-08-17 Revised : 2013-04-19

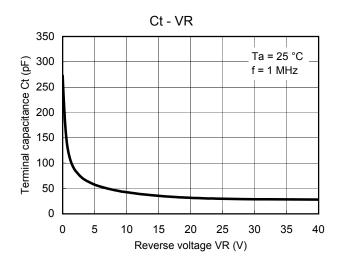


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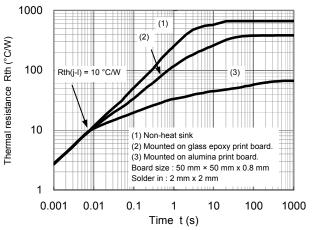
Technical Data (reference)

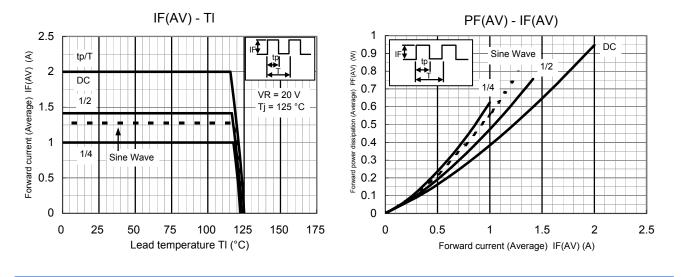






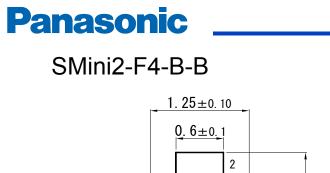
Rth - t





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 1.9 ± 0.1

 0.3 ± 0

1

0.8±0.1

2. 5±0.⁻

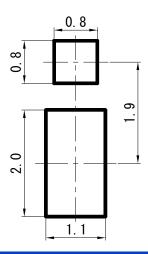
 55 ± 0.05

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Land Pattern (Reference) (Unit: mm)

(5°)



DB2141300L

Schottky Barrier Diode

0 to 0.1

Unit: mm

Established : 2009-08-17 Revised : 2013-04-19

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